



# AMP2018A SOLID STATE HIGH POWER AMPLIFIER

## FEATURES

- Class A/AB linear GaN design
- Instantaneous wide bandwidth
- Rack mounted system
- Designed for broadband EMI/RFI, Lab, Comm. and EW applications
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



## ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	800 - 2000 MHz	
Power Output CW	20 Watt Min / 30 Watt Typ	CW
Power Output @ P1dB	10 Watt Min	
Power Gain	43 dB Min	
Power Gain Flatness	3.0 dB p-p Max	Constant input power
Input Return Loss	-10dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	<-30 dBc Typ	33dBm/Tone, Δ = 1MHz
Harmonics	<-25 dBc Typ	At rated Pout
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	100 - 240 VAC	
Power Consumption	150 Watt Max	At rated Pout
Input Power Protection	+8 dBm Max	<10 Sec without damage
Load VSWR Protection	∞ : 1	<1 min at rated Pout

## ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

## MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 562 mm	2U - Excluding handles
Weight	9 kg.	
RF Connectors In/Out	Type-N Female	Front or rear panel
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	Or equivalent
Cooling	Built in Fan Cooling	
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485, USB Optional GPIB Interface	Optional Remote Bluetooth application

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## OUTLINE DRAWING

